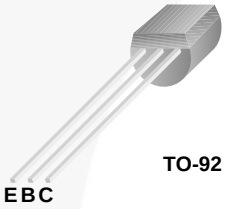
October 2014

2N3904 / MMBT3904 / PZT3904
NPN General-Purpose Amplifier

Description

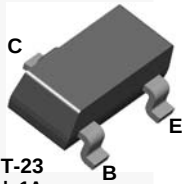
This device is designed as a general-purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

2N3904



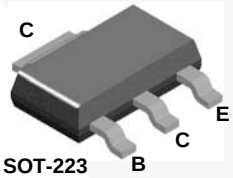
TO-92

MMBT3904



SOT-23
Mark:1A

PZT3904



SOT-223

Ordering Information

Part Number	Marking	Package	Packing Method	Pack Quantity
2N3904BU	2N3904	TO-92 3L	Bulk	10000
2N3904TA	2N3904	TO-92 3L	Ammo	2000
2N3904TAR	2N3904	TO-92 3L	Ammo	2000
2N3904TF	2N3904	TO-92 3L	Tape and Reel	2000
2N3904TFR	2N3904	TO-92 3L	Tape and Reel	2000
MMBT3904	1A	SOT-23 3L	Tape and Reel	3000
PZT3904	3904	SOT-223 4L	Tape and Reel	2500

Absolute Maximum Ratings(1), (2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CEO}	Collector-Emitter Voltage	40	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	6.0	V
I_C	Collector Current - Continuous	200	mA
$T_{J,}$ T_{STG}	Operating and Storage Junction Temperature Range	-55 to 150	°C

Notes:

1. These ratings are based on a maximum junction temperature of 150°C.
2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty cycle operations.

Thermal Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Maximum			Unit
		2N3904	MMBT3904(3)	PZT3904(4)	
P_D	Total Device Dissipation	625	350	1,000	mW
	Derate Above 25°C	5.0	2.8	8.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

Notes:

3. Device is mounted on FR-4 PCB 1.6 inch X 1.6 inch X 0.06 inch.
4. Device is mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm, mounting pad for the collector lead minimum 6 cm^2.

Electrical Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I_C = 1.0 mA, I_B = 0	40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C = 10 μA, I_E = 0	60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E = 10 μA, I_C = 0	6.0		V
I_{BL}	Base Cut-Off Current	V_{CE} = 30 V, V_{EB} = 3 V		50	nA
I_{CEX}	Collector Cut-Off Current	V_{CE} = 30 V, V_{EB} = 3 V		50	nA
ON CHARACTERISTICS[5]					
h_{FE}	DC Current Gain	I_C = 0.1 mA, V_{CE} = 1.0 V	40		
		I_C = 1.0 mA, V_{CE} = 1.0 V	70		
		I_C = 10 mA, V_{CE} = 1.0 V	100	300	
		I_C = 50 mA, V_{CE} = 1.0 V	60		
		I_C =100 mA, V_{CE} = 1.0V	30		
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = 10 mA, I_B = 1.0 mA		0.2	V
		I_C = 50 mA, I_B = 5.0 mA		0.3	
V_{BE}(sat)	Base-Emitter Saturation Voltage	I_C = 10 mA, I_B = 1.0 mA	0.65	0.85	V
		I_C = 50 mA, I_B = 5.0 mA		0.95	
SMALL SIGNAL CHARACTERISTICS					
f_T	Current Gain - Bandwidth Product	I_C = 10 mA, V_{CE} = 20 V, f = 100 MHz	300		MHz
C_{obo}	Output Capacitance	V_{CB} = 5.0 V, I_E = 0, f = 100 kHz		4.0	pF
C_{ibo}	Input Capacitance	V_{EB} = 0.5 V, I_C = 0, f = 100 kHz		8.0	pF
NF	Noise Figure	I_C = 100 μA, V_{CE} = 5.0 V, R_S = 1.0 kΩ, f = 10 Hz to 15.7 kHz		5.0	dB
SWITCHING CHARACTERISTICS					
t_d	Delay Time	V_{CC} = 3.0 V, V_{BE} = 0.5 V I_C = 10 mA, I_{B1} = 1.0 mA		35	ns
t_r	Rise Time			35	ns
t_s	Storage Time	V_{CC} = 3.0 V, I_C = 10 mA, I_{B1} = I_{B2} = 1.0 mA		200	ns
t_f	Fall Time			50	ns

Note:

5. Pulse test: pulse width ≤ 300 μs, duty cycle ≤ 2.0%.

Typical Performance Characteristics

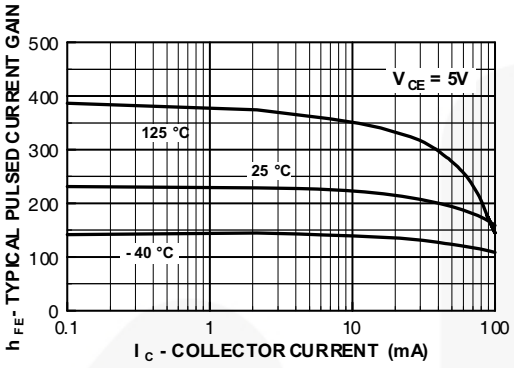


Figure 1. Typical Pulsed Current Gain vs. Collector Current

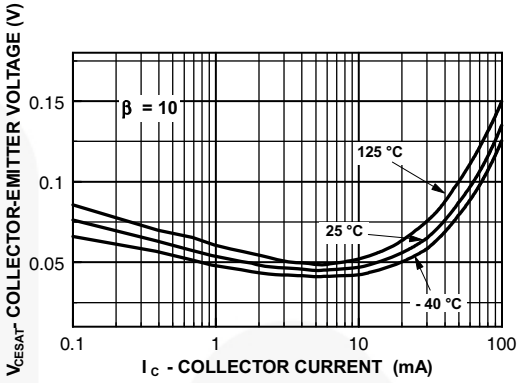


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

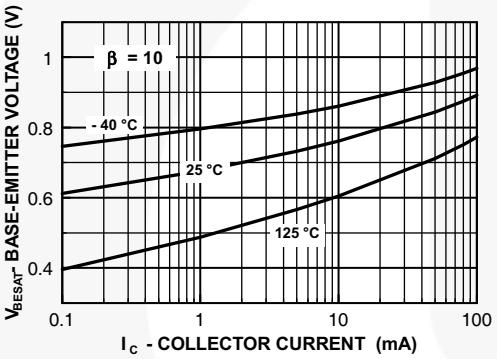


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

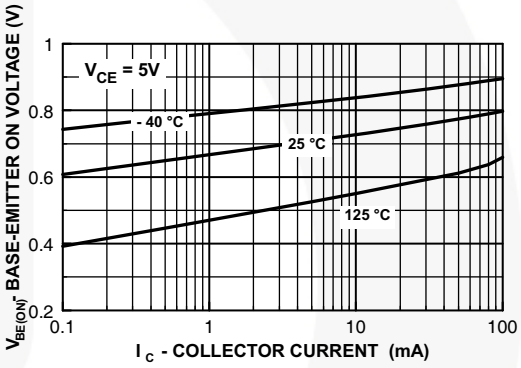


Figure 4. Base-Emitter On Voltage vs. Collector Current

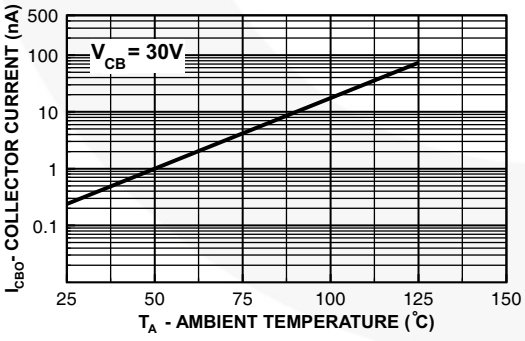


Figure 5. Collector Cut-Off Current vs. Ambient Temperature

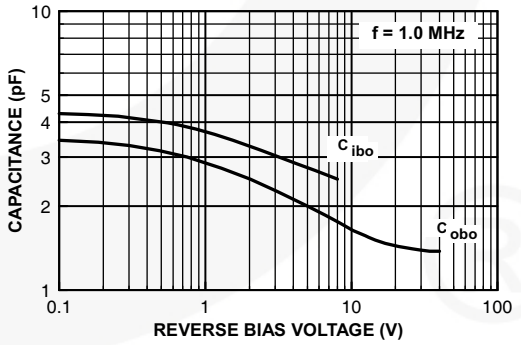


Figure 6. Capacitance vs. Reverse Bias Voltage

Typical Performance Characteristics (Continued)

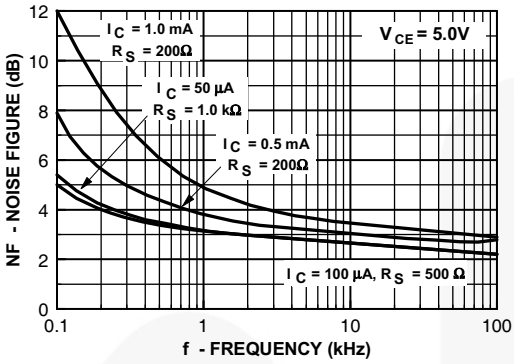


Figure 7. Noise Figure vs. Frequency

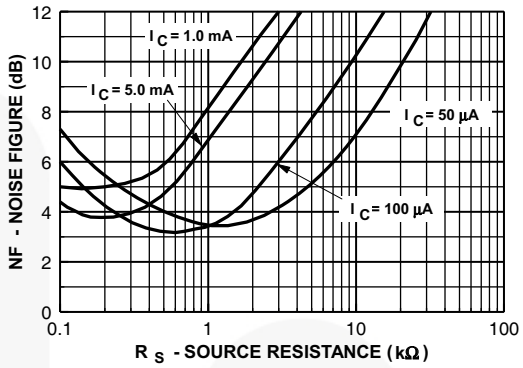


Figure 8. Noise Figure vs. Source Resistance

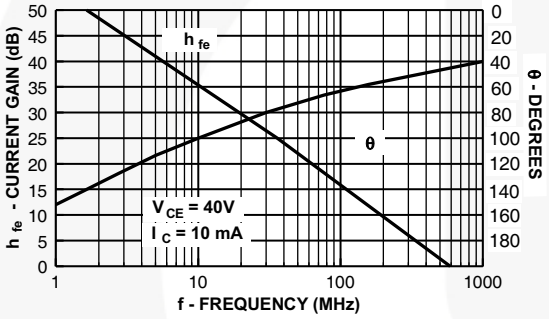


Figure 9. Current Gain and Phase Angle vs. Frequency

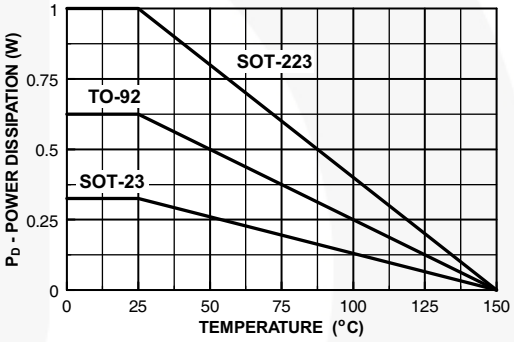


Figure 10. Power Dissipation vs. Ambient Temperature

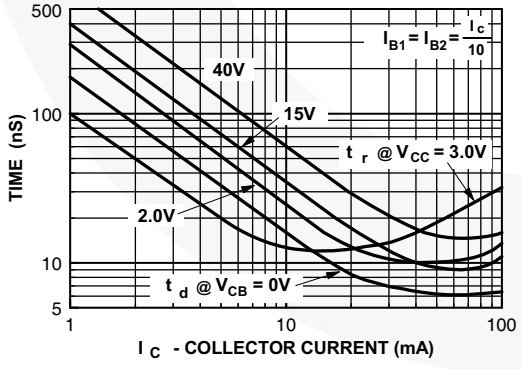


Figure 11. Turn-On Time vs. Collector Current

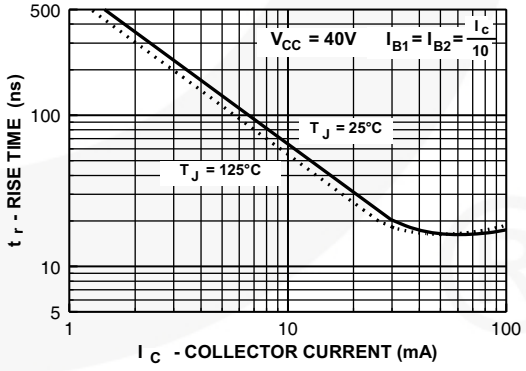


Figure 12. Rise Time vs. Collector Current

Typical Performance Characteristics (Continued)

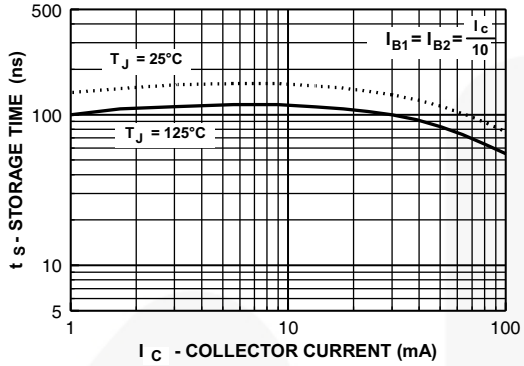


Figure 13. Storage Time vs. Collector Current

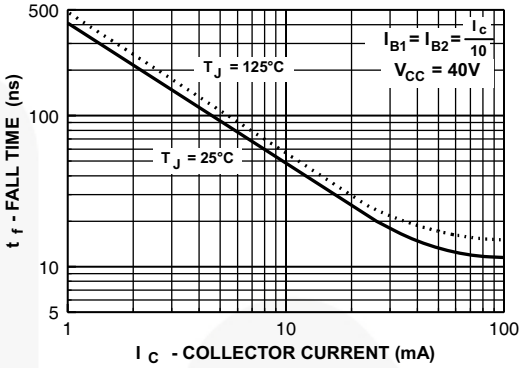


Figure 14. Fall Time vs. Collector Current

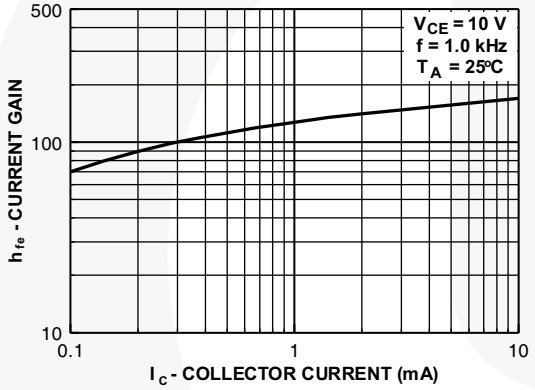


Figure 15. Current Gain

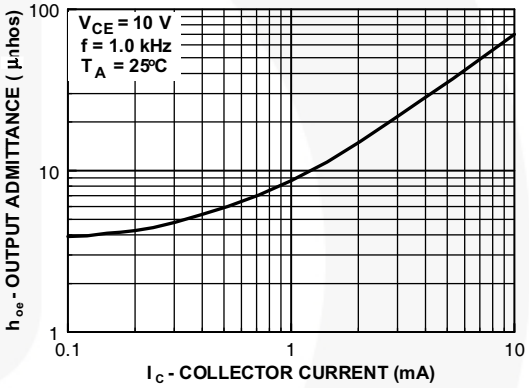


Figure 16. Output Admittance

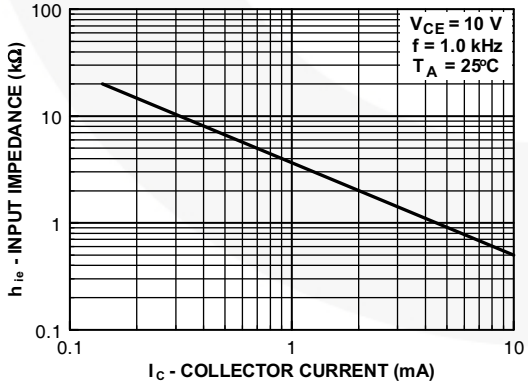


Figure 17. Input Impedance

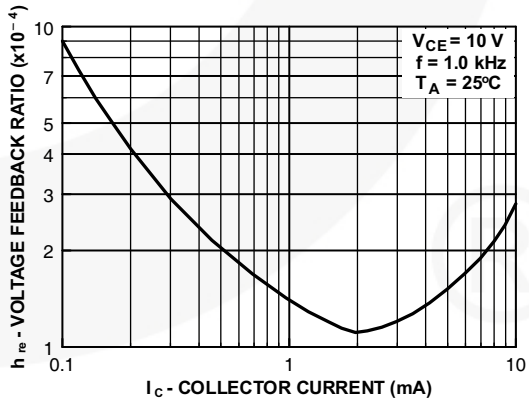


Figure 18. Voltage Feedback Ratio

Test Circuits

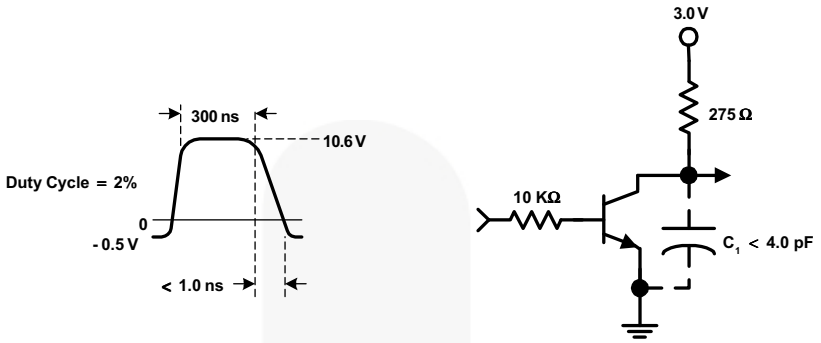


Figure 19. Delay and Rise Time Equivalent Test Circuit

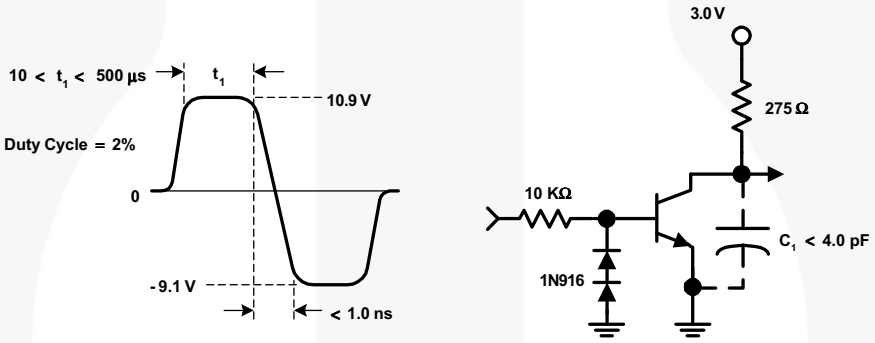
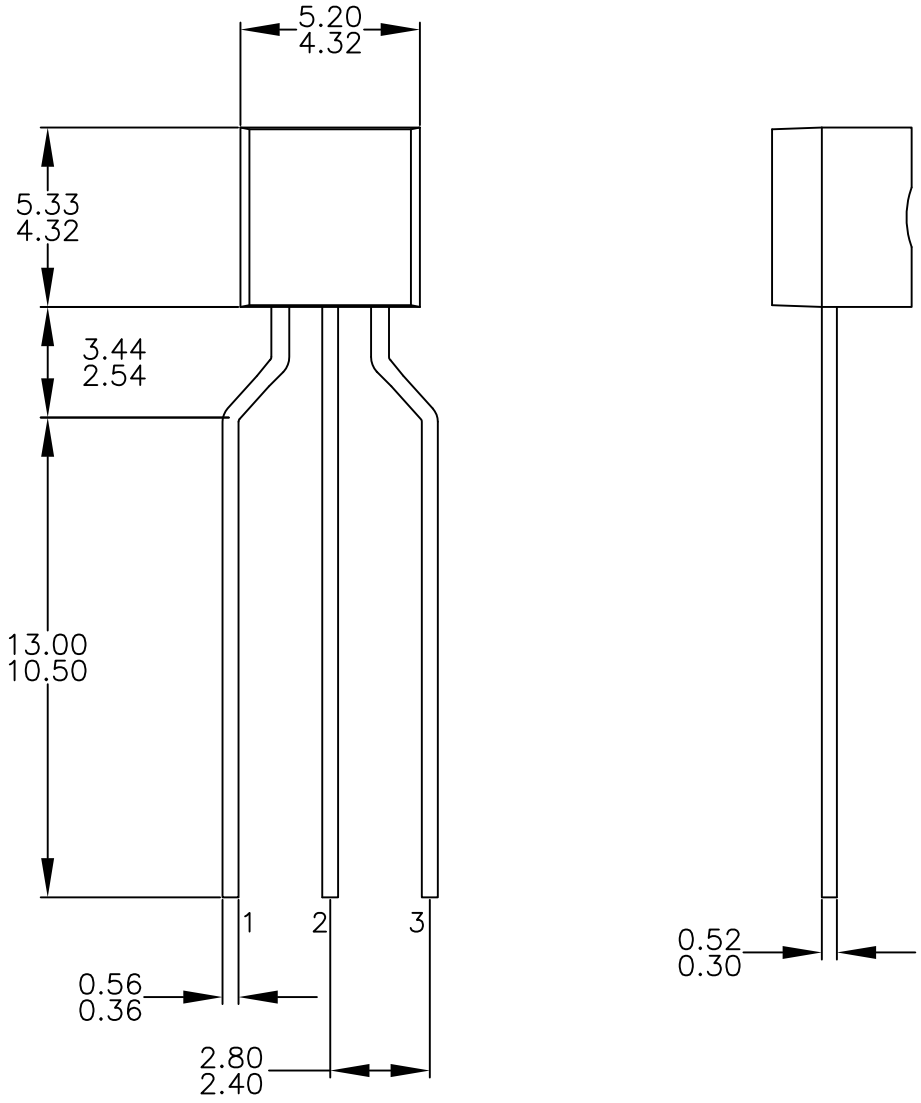
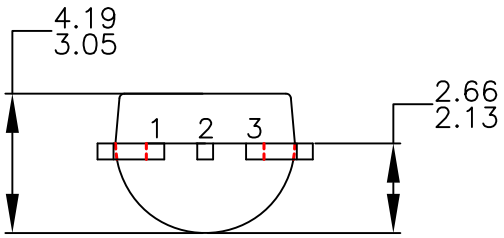


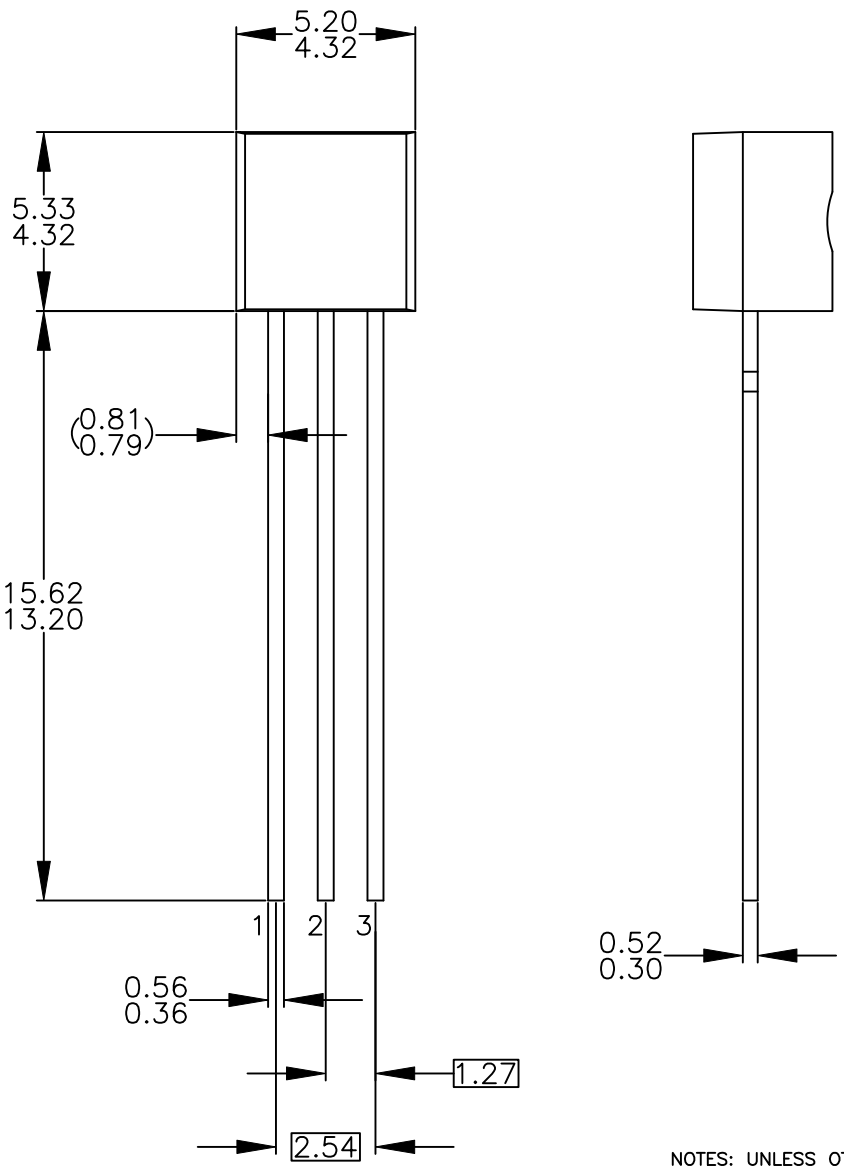
Figure 20. Storage and Fall Time Equivalent Test Circuit

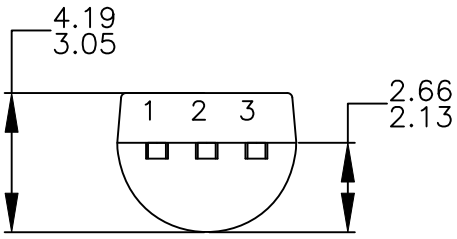




NOTES: UNLESS OTHERWISE SPECIFIED

A. DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC.
B. ALL DIMENSIONS ARE IN MILLIMETERS.
C. DRAWING CONFORMS TO ASME Y14.5M-2009.
D. DRAWING FILENAME: MKT-ZA03FREV3.
E. FAIRCHILD SEMICONDUCTOR.

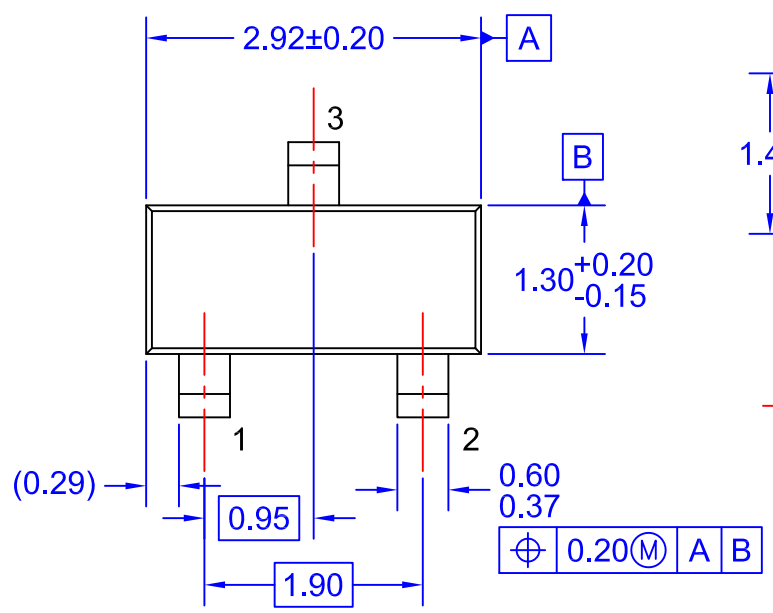


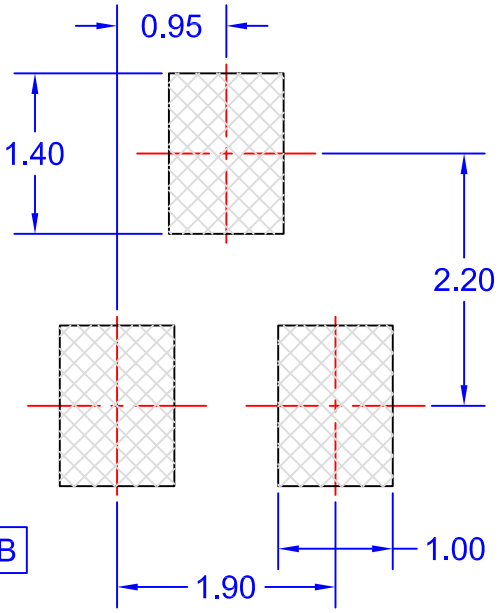


NOTES: UNLESS OTHERWISE SPECIFIED

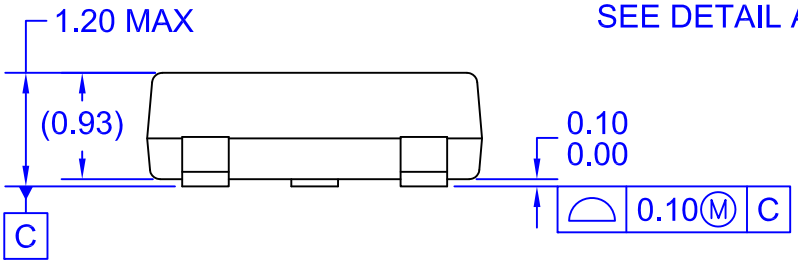
A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DRAWING CONFORMS TO ASME Y14.5M-2009.
D) DRAWING FILENAME: MKT-ZA03DREV4.

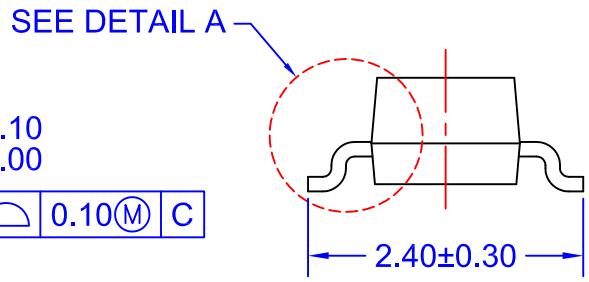
FAIRCHILD

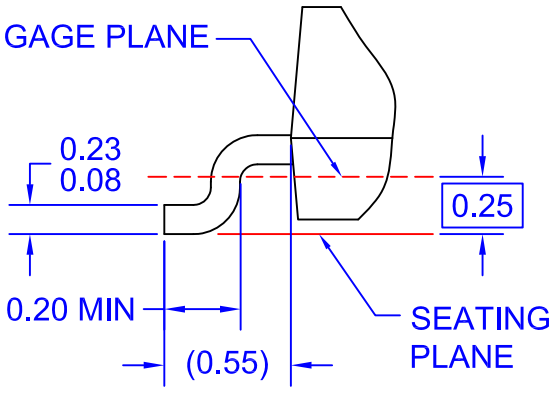




LAND PATTERN
RECOMMENDATION







DETAIL A
SCALE: 2X

NOTES: UNLESS OTHERWISE SPECIFIED

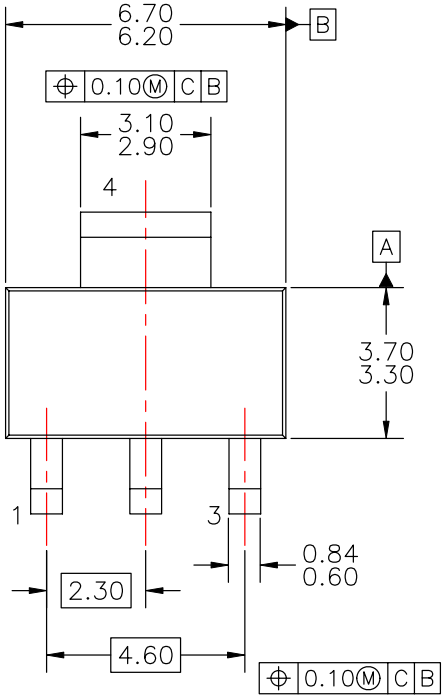
A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 2009.
E) DRAWING FILE NAME: MA03DREV12

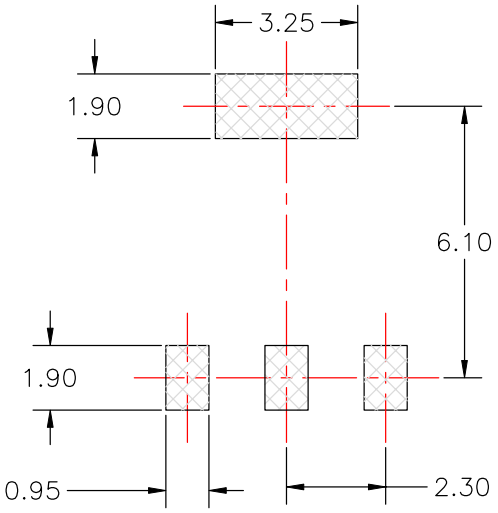
FAIRCHILD™

APPROVED
July-14-2008

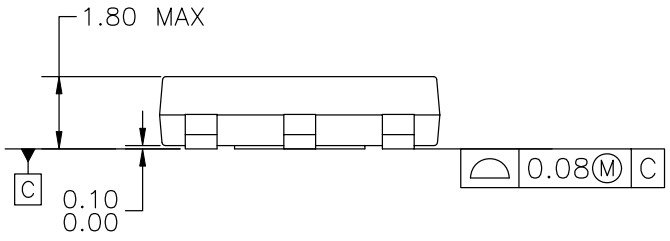
REVISIONS

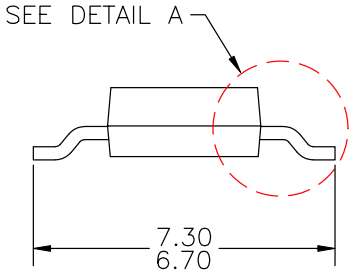
LTR	DESCRIPTION	DATE	NAME/SITE
A	RELEASE TO DOCUMENT CONTROL	JAN.25,1996	TL/FSCP
2	CHG DWG TEMPLATE FR NATIONAL TO FAIRCHILD; CHG DIM STYLE FR DUAL INCH[MM] TO SINGLE, MM; CHG LD WID FR $0.74^{+0.05}_{-0.07}$ TO 0.60–0.84; REMOVE PKG THICK DIM (1.6); CHG TOTAL PKG HT FR $1.80^{}_{1.20}$ TO 1.80 MAX; CHG FOOT LANDING DIM FR 0.91 MIN TO 0.60 MIN; CHG LD THICKNESS FR $0.3^{+0.09}_{-0.07}$ TO 0.20–0.35; ADD DRAFT ANGLE OF MOLDED BODY TOP & BOT; CHG LD LGTH TO PKG EDGE DIM TO BASIC; CHG LD PITCH FR 2.29 BS TO 2.30 BS; CHG BODY WID FR $3.56^{+0.18}_{-0.38}$ TO $3.70^{}_{3.30}$; CHG BODY LN FR $6.5^{+0.3}_{-0.4}$ TO $6.70^{}_{6.30}$; CHG TOTAL PKG WID FR $6.96^{+0.33}_{-0.38}$ TO $7.30^{}_{6.70}$; CHG PAD SIZE FR 0.99 MAX TO 0.95; CHG PAD PITCH FR 2.286 TO 2.30; CHG THERMAL TAB SIZE FR 3.28 MAX TO 3.25; CHG PAD SIZE FR 1.5 TO 1.90; CHG PAD SPACE FR 6.3 TO 6.10; CHG NOTE '2' TO 'A' W/O DATE; DEL NOTE ON LD FINISH; ADD NOTES B, C, D, E & F.	12FEB08	LZSC/FSCP

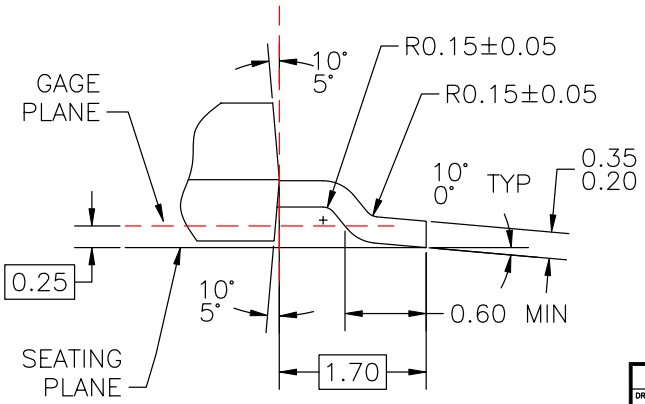




LAND PATTERN RECOMMENDATION







DETAIL A
SCALE: 2:1

NOTES: UNLESS OTHERWISE SPECIFIED

A) DRAWING BASED ON JEDEC REGISTRATION TO–261, VARIATION AA.
B) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
C) ALL DIMENSIONS ARE IN MILLIMETERS.
D) DRAWING CONFORMS TO ASME Y14.5M–1994.
E) LANDPATTERN NAME: SOT230P700X180–4BN
F) DRAWING FILENAME: MKT–MA04AREV2

APPROVALS	DATE
DRAWN: J.U. COMPARATIVO JR.	26FEB2008
CHECKED: L.Z. STA CRUZ	
APPROVED: M.R. GESTOLE	
G.S. BAJE	

PROJECTION INCH [MM]

FAIRCHILD SEMICONDUCTOR TM

MOLDED PACKAGE
SOT–223, 4 LEAD

SCALE	SIZE	DRAWING NUMBER	REV
1:1	A3	MKT–MA04A	2

FORMERLY: N/A

SHEET : 1 OF 1

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™
AttitudeEngine™
Awinda®
AX-CAP®*
BitSiC™
Build it Now™
CorePLUS™
CorePOWER™
CROSSVOLT™
CTL™
Current Transfer Logic™
DEUXPEED®
Dual Cool™
EcoSPARK®
EfficientMax™
ESBC™
Fairchild®
Fairchild Semiconductor®
FACT Quiet Series™
FACT®
FastvCore™
FETBench™
FPS™
F-PFS™
FRFET®
Global Power Resource SM
GreenBridge™
Green FPS™
Green FPS™ e-Series™
G*max*™
GTO™
IntelliMAX™
ISOPLANAR™
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®
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™
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